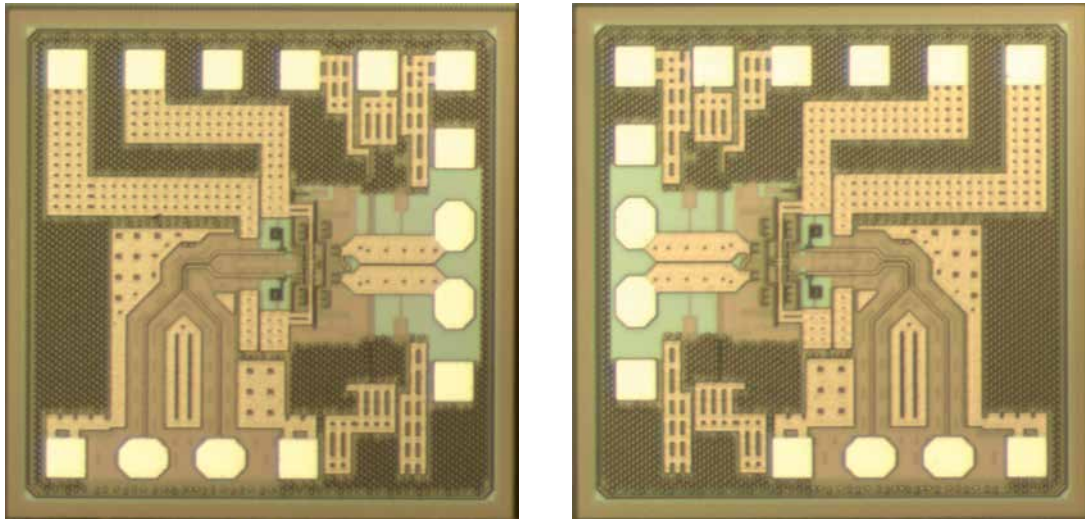


LOW-POWER 32 GBd LINEAR OPTICAL MODULATOR DRIVER



AT A GLANCE

32 GBd linear differential driver for telecom and datacom applications

Features

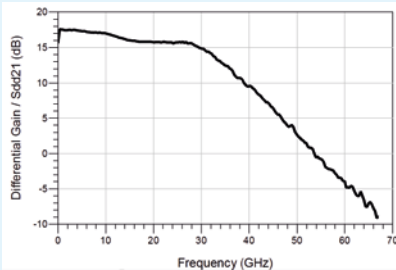
- Differential input and differential output
- Open-collector outputs
- Ultra-low power, 270 mW
- Linear Driver
- 3.0V_{pp} differential output at 2 x 25 Ω loads
- Integrated output peak-level detectors
- 90°-bended RF input, mirrored IC available

Applications

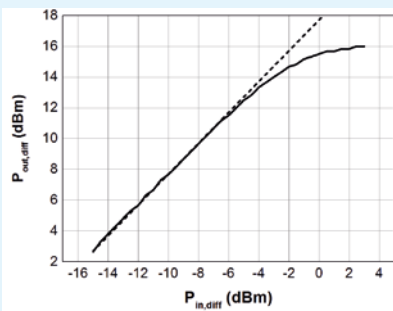
- Mach-Zehnder modulator driver
- Supports NRZ, PAM-4 Signals
- Broadband signal amplification

Low-power open-collector SiGe Driver IC

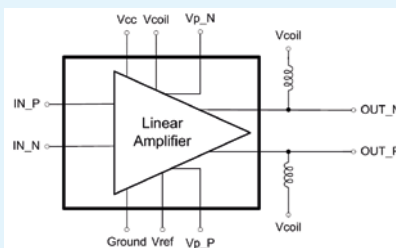
HHI provides open-collector SiGe linear driver IC for InP Mach-Zehnder modulator. Its differential output is suitable to drive InP Mach-Zehnder modulator having 2x 25 Ω. It integrates output peak-level detectors and consumes 270 mW per channel. It enables the electro-optical module to consume the lowest power.



Differential S21 measurement result
($P_{in,diff} = -20\text{dBm}$, $Temp = 23^\circ\text{C}$,
 $Z_{in,diff} = 100\Omega$, $Z_{Load,diff} = 50\Omega$)



1-dB compression point at 1 GHz (40°C)



Circuit Block Diagram

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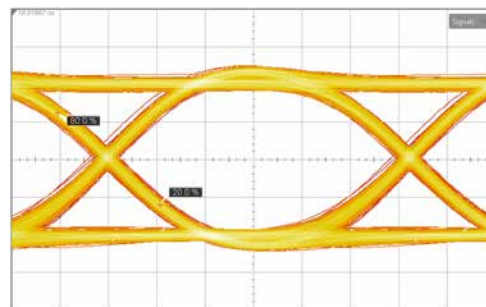
Fraunhofer Heinrich Hertz Institute
Einsteinufer 37, 10587 Berlin
Germany

www.hhi.fraunhofer.de/pc/rese

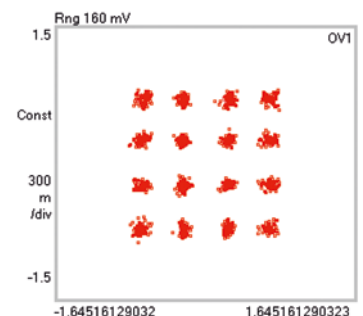
Specifications

Parameter	Symbol	Min	Typ	Max	Unit	Conditions	
Bandwidth	BW		30		GHz		
Power	P		270		mW		
Data Rate	DR		32		Gb/s		
Rise / fall time	t/t_f		10		ps	20 % -80 %	
Gain*			17.5		dB	Differential S_{21} $Z_{in,diff} = 100\Omega$, $Z_{Load,diff} = 50\Omega$	
Group Delay Distortion*	GD			± 5	ps		
Jitter (rms)			523		fs		
Jitter(p-p)			3.47		ps		
Differential Input Signal	$V_{IN,P} - V_{IN,N}$		600		mV _{pp}	AC-coupled	
Differential Output Signal	$V_{OUT,P} - V_{OUT,N}$		3000		mV _{pp}	2 x 25 Ω load	
P_{1dB}	P_{1dB}	13,6		14,4	dBm	output-referred, $Z_{Load,diff} = 50\Omega$	
THD	THD		3.7		%	1 GHz, 3V _{pp} output conditions	
CMRR*	CMRR		14		dB	up to 20 GHz	
Input Reflection*	S_{dd11}			DC < f < 8 GHz 8 GHz < f < 24 GHz 24 GHz < f < BW	-19 -9 -8	dB	Differential input
Output Peak-level detector			170 mV		V/V _{pp,diff}	$Z_{Load,diff} = 50\Omega$, each output (V_{p_N} , V_{p_P}) referenced to Vref	
Operation Temperature			40		$^\circ\text{C}$		

* denotes that measurements were carried out at room temperature condition, 23°C. Unless noted, measurement temperature is 40°C.



Electrical eye waveform at 32 Gb/s
(5ps/div, 700mV/div, 40°C)



Electro-optical QAM-16 Constellation at 32 Gb/s, EVM: 6.4%rms